

# Microelectronics Circuit Analysis and Design

Donald A. Neamen

## Chapter 6

### Basic BJT Amplifiers

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Chapter 6-1

In this chapter, we will:

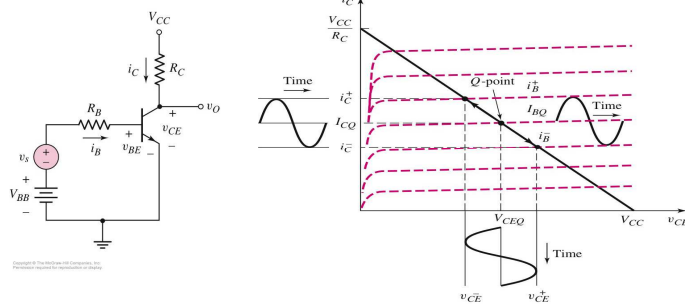
- Understand the principle of a linear amplifier.
- Discuss and compare the three basic transistor amplifier configurations.
  - the common-emitter amplifier.
  - the emitter-follower amplifier.
  - the common-base amplifier.
- Analyze multi-transistor amplifiers.

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Chapter 6-2

## Common Emitter with Time-Varying Input

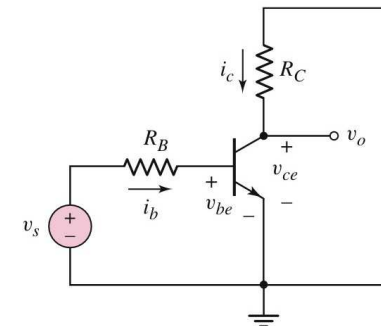


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## ac Equivalent Circuit for Common Emitter



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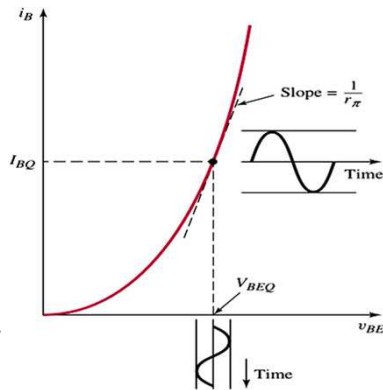
## $I_B$ Versus $V_{BE}$ Characteristic

$$v_{BE} = V_{BE} + v_{be}$$

$$i_B = I_{BQ} \exp(v_{be}/V_T)$$

$$e^x \cong 1 + x + \dots$$

$$i_B \cong I_{BQ} \left(1 + \frac{v_{be}}{V_T}\right) = I_{BQ} + i_b$$



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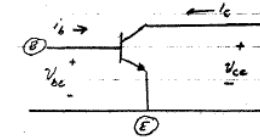
## ac Equivalent Circuit

### Assumptions

1. 'Q' is biased in Forward Active Mode
2. AC VOLTAGES ARE "Small Signals"

### A. HYBRID $\pi$ Equivalent Ckt

#### TWO PORT NETWORK FOR CC CKT



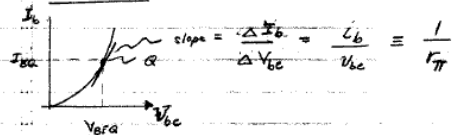
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## ac Equivalent Circuit

### 1. INPUT PORT



$v_{be} = i_b r_{\pi}$  is the small signal linear constant of proportionality between  $v_{be}$  &  $i_b$

$r_{\pi} \equiv$  DIFFUSION RESISTANCE or b-e input resistance.

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## ac Equivalent Circuit

Mathematically we have:

$$\frac{1}{r_{\pi}} = \left. \frac{\partial i_B}{\partial V_{BE}} \right|_{Qpt} = \frac{2}{2V_{BE}} \left[ \frac{I_S}{\beta_F} e^{V_{BE}/V_T} \right] \bigg|_{Qpt} = \frac{1}{V_T} \left[ \right] = \frac{I_{BQ}}{V_T}$$

So:  $r_{\pi} = \frac{V_{BE}}{I_{BQ}} = \frac{V_T}{I_{BQ}} = \frac{\beta_F V_T}{I_{CQ}}$

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## ac Equivalent Circuit

2. Output Port

- Let  $i_c$  be independent of  $v_{ce}$  [neglect Early Effect]

Since  $\Delta i_c = \left. \frac{\partial i_c}{\partial i_b} \right|_{a-p}$

$$= \left. \frac{\partial i_c}{\partial i_b} \right|_{a-p} \cdot i_b$$

Define  $\beta = \left. \frac{\partial i_c}{\partial i_b} \right|_{a-p} = \text{AC C-E CURRENT GAIN}$

then we write

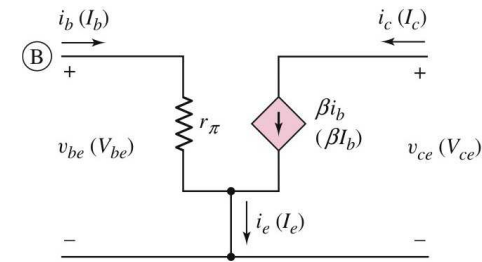
$$i_c = \beta i_b$$

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## Small-Signal Equivalent Circuit Using Common-Emitter Current Gain

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## ac Equivalent Circuit

the transconductance  $g_m$ Since  $v_{be}$  and  $i_b$  are related by  $r_{\pi}$ , we canequally represent  $i_c$  as a function of  $v_{be}$ 

$$i_c = \left. \frac{\partial i_c}{\partial v_{be}} \right|_{a-p} \cdot v_{be}$$

Define  $g_m = \left. \frac{\partial i_c}{\partial v_{be}} \right|_{a-p} = \frac{I_{CQ}}{V_T}$

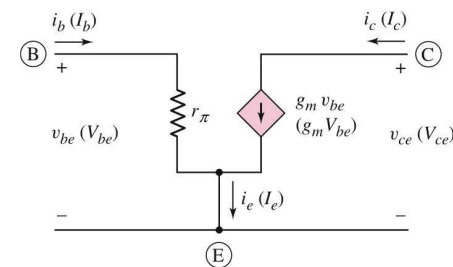
$$i_b = i_b e^{v_{be}/V_T}$$

$$\frac{\partial i_b}{\partial v_{be}} = \frac{1}{V_T} \cdot I_{CQ}$$

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Small-Signal Hybrid  $\pi$  Model for npn BJTCopyright © The McGraw-Hill Companies, Inc.  
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Phasor signals are shown in parentheses.

$$g_m = \frac{I_{CQ}}{V_T}$$

$$r_{\pi} = \frac{\beta V_T}{I_{CQ}}$$

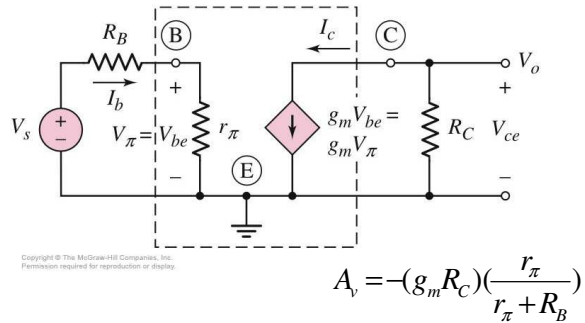
$$g_m r_{\pi} = \beta$$

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### Small-Signal Equivalent Circuit for npn Common Emitter circuit



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### Problem-Solving Technique: BJT AC Analysis

1. Analyze circuit with only dc sources to find Q point.
2. Replace each element in circuit with small-signal model, including the hybrid  $\pi$  model for the transistor.
3. Analyze the small-signal equivalent circuit after setting dc source components to zero.

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### Transformation of Elements

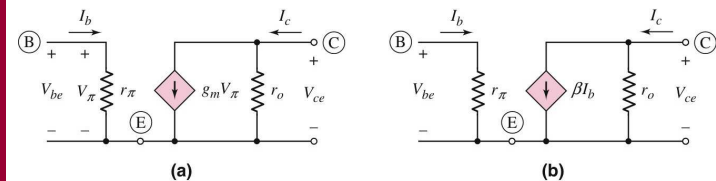
| Element                             | DC Model             | AC Model        |
|-------------------------------------|----------------------|-----------------|
| Resistor                            | R                    | R               |
| Capacitor                           | Open                 | C               |
| Inductor                            | Short                | L               |
| Diode                               | $+V_T$ $r_f$ $-$<br> | $r_d = V_T/I_D$ |
| Independent Constant Voltage Source | $+V_S$ $-$<br>       | Short           |
| Independent Constant Current Source | $I_S$                | Open            |

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### Hybrid $\pi$ Model for npn with Early Effect



$$r_o = \frac{V_A}{I_{CQ}}$$

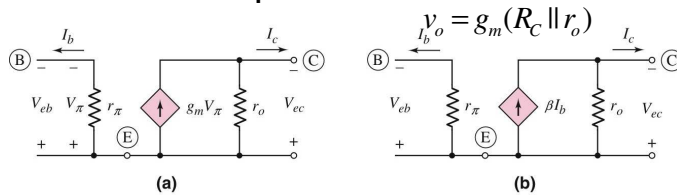
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## Hybrid p Model for pnp with Early Effect

All voltage and current polarities are reversed.  
Gain equation are the SAME.



$$v_o = g_m v_\pi (R_C \parallel r_o)$$

$$v_o = \beta i_b (R_C \parallel r_o)$$

$$v_\pi = -v_s \left( \frac{r_\pi}{r_\pi + R_B} \right)$$

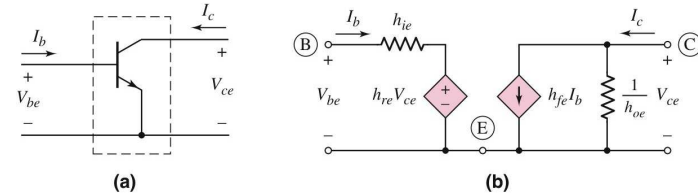
$$i_b = \left( \frac{-v_s}{r_\pi + R_B} \right)$$

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## h-Parameter Model for npn



$$V_{be} = h_{ie} I_b + h_{re} V_{ce}$$

KVL at input loop

$$I_c = h_{fe} I_b + h_{oe} V_{ce}$$

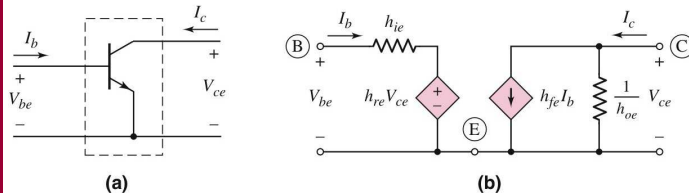
KCL at output loop

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## h-Parameter Model for npn



$$h_{ie} = r_b + r_\pi \parallel r_\mu$$

$$h_{fe} = \beta$$

$$h_{re} \cong \frac{r_\pi}{r_\mu}$$

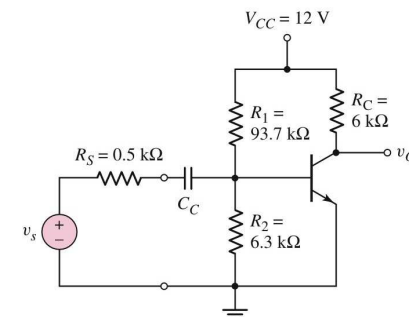
$$h_{oe} = \frac{1 + \beta}{r_\mu} + \frac{1}{r_o}$$

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## Common Emitter with Voltage-Divider Bias and a Coupling Capacitor

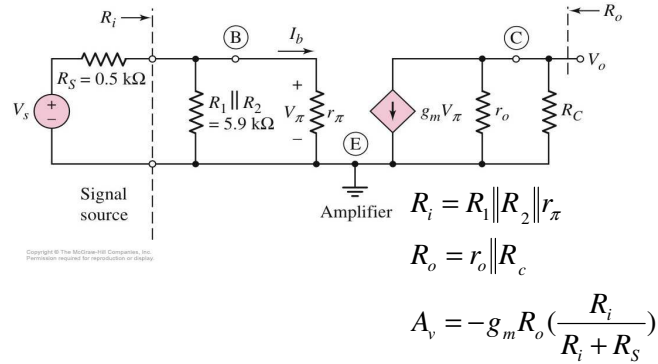


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### Small-Signal Equivalent Circuit – Coupling Capacitor assumed a Short

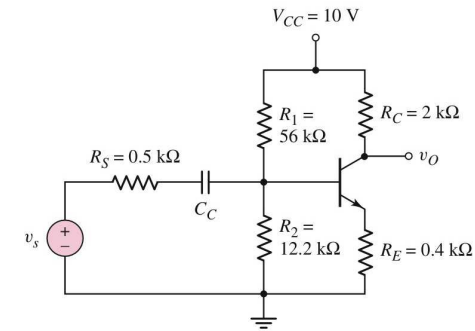


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### nnp Common Emitter with Emitter Resistor

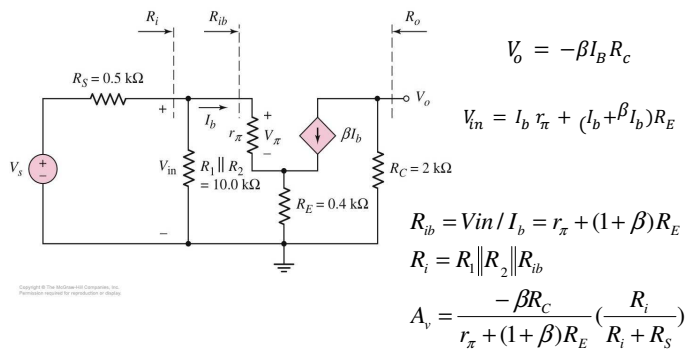


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### Small-Signal Equivalent Circuit: Common Emitter with $R_E$

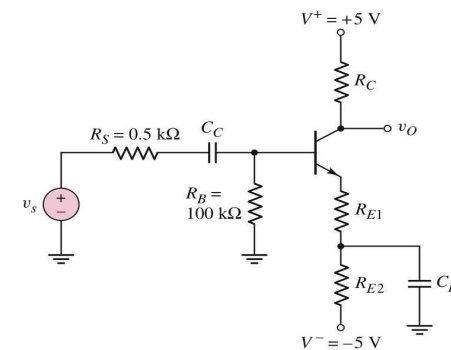


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### $R_E$ and Emitter Bypass Capacitor

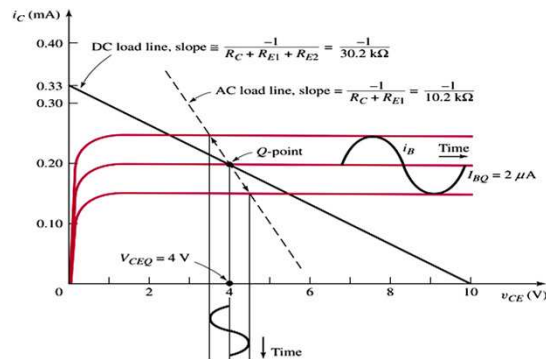


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## DC and AC Load Lines: $R_E$ and Emitter Bypass Capacitor



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## Problem-Solving Technique: Maximum Symmetrical Swing

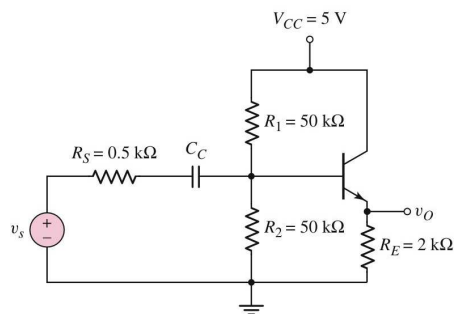
1. Write dc load line equation that relates  $I_{CQ}$  and  $V_{CEQ}$ .
2. Write ac load line equations that relates  $i_c$  and  $v_{ce}$
3. In general,  $i_c = I_{CQ} - I_{C(\min)}$ , where  $I_{C(\min)}$  is zero or other minimum collector current.
4. In general,  $v_{ce} = V_{CEQ} - V_{CE(\min)}$ , where  $V_{CE(\min)}$  is some specified minimum collector-emitter voltage.
5. Combine above 4 equations to find optimum  $I_{CQ}$  and  $V_{CEQ}$ .

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## Common-Collector or Emitter-Follower Amplifier

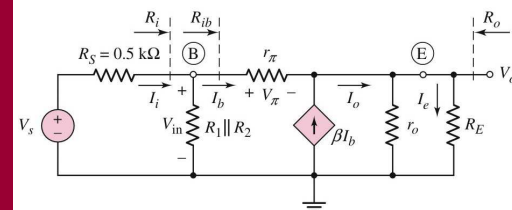


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## Small-Signal Equivalent Circuit: Emitter Follower



$$I_o = (1 + \beta) I_b \quad \text{so} \quad v_o = I_o (1 + \beta) (r_o \parallel R_E)$$

$$v_o = I_b [r_\pi + (1 + \beta) (r_o \parallel R_E)]$$

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### Small-Signal Equivalent Circuit: Emitter Follower

$$I_o = (1+\beta)I_b \quad \text{or} \quad V_o = I_b(1+\beta)(r_o \parallel R_E)$$

$$V_{in} = I_b [r_\pi + (1+\beta)(r_o \parallel R_E)]$$

$$R_{ib} = \frac{V_{in}}{I_b} = r_\pi + (1+\beta)(r_o \parallel R_E)$$

$$R_{in} = R_1 \parallel R_2 \parallel R_{ib} \quad \text{Typically a large value due to the reflected impedance}$$

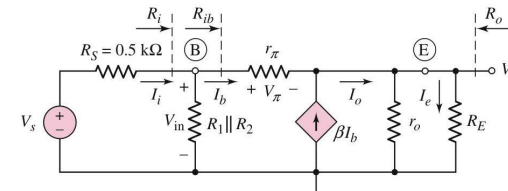
$$V_{in} = \left( \frac{R_{in}}{R_{in} + R_s} \right) \cdot V_s$$

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### S-S Equivalent : Emitter Follower



$$A_v = \frac{V_o}{V_s} = \frac{I_b(1+\beta)(r_o \parallel R_E)}{I_b [r_\pi + (1+\beta)(r_o \parallel R_E)] \left( \frac{R_{in}}{R_{in} + R_s} \right)}$$

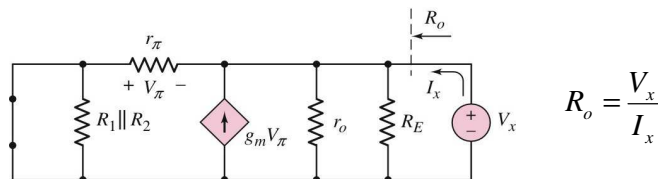
$$A_v = \frac{(1+\beta)(r_o \parallel R_E)}{r_\pi + (1+\beta)(r_o \parallel R_E)} \left( \frac{R_{in}}{R_{in} + R_s} \right) \cong 1$$

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### Output Resistance: Emitter Follower



$$R_o = r_o \parallel R_E \parallel (\text{base circuit reflected into emitter})$$

$$R_o = \frac{r_\pi}{1+\beta} \parallel R_E \parallel r_o \quad \text{Typically a low value due to the reflected impedance}$$

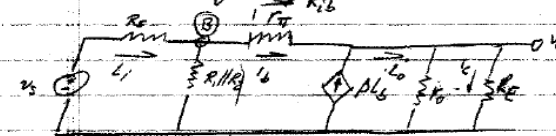
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### Emitter Follower Current Gain

Recall the small signal Emitter follower circuit:



$$I_b = \left( \frac{R_1 \parallel R_2}{R_1 \parallel R_2 + R_{ib}} \right) I_i \quad \leftarrow \text{current divider}$$

$$I_o = (1+\beta)I_b = (1+\beta) \left( \frac{R_1 \parallel R_2}{R_1 \parallel R_2 + R_{ib}} \right) I_i$$

$$\text{Then } I_e = \left( \frac{r_o}{r_o + R_E} \right) I_o$$



## Emitter Follower Current Gain

So finally:

$$A_i = \frac{i_e}{i_i} = (1+\beta) \left( \frac{R_E \parallel R_L}{R_E \parallel R_L + R_{ib}} \right) \left( \frac{r_o}{r_o + R_E} \right)$$

assuming  $R_E \parallel R_L \gg R_{ib} \Rightarrow \text{Then } ① \approx 1$

and if  $r_o \gg R_E \Rightarrow \text{Then } ② \approx 1$

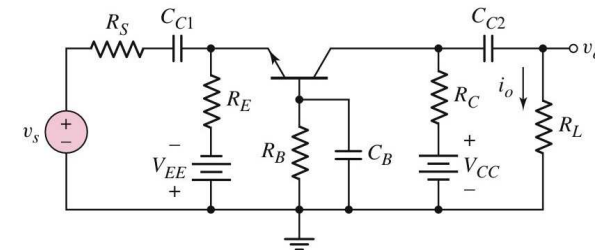
and  $A_i \approx (1+\beta)$

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## Common-Base Amplifier

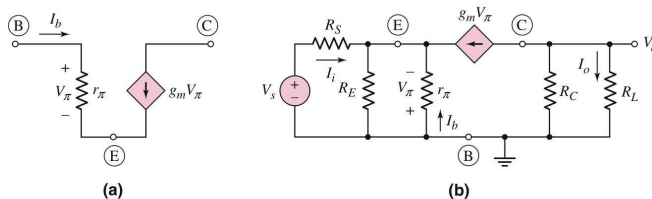


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## Small-Signal Equivalent Circuit: Common Base



$$A_v \approx g_m (R_C \parallel R_L)$$

$$A_i = g_m \left( \frac{R_C}{R_C + R_L} \right) \left[ \frac{r_{\pi}}{1+\beta} \parallel R_E \right]$$

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## Small-Signal Equivalent Circuit: Common Base

$$\Delta \quad v_o = -g_m v_{\pi} (R_C \parallel R_L)$$

now need  $v_{\pi}$  in terms of  $v_s$

KCL at Emitter node: Assume all current enters the emitter.

$$\frac{v_s - (-v_{\pi})}{R_S} + \frac{v_{\pi}}{R_E} + \frac{v_{\pi}}{r_{\pi}} + g_m v_{\pi} = 0$$

$$\frac{v_s}{R_S} + v_{\pi} \left( g_m + \frac{1}{r_{\pi}} + \frac{1}{R_E} + \frac{1}{R_S} \right) = 0 \quad \left\{ \begin{array}{l} \text{note } g_m r_{\pi} = \beta \\ \text{so: } g_m = \beta / r_{\pi} \end{array} \right.$$

$$v_{\pi} \left( \frac{\beta+1}{r_{\pi}} + \frac{1}{R_E} + \frac{1}{R_S} \right) = -\frac{v_s}{R_S}$$

$$v_{\pi} = -\frac{v_s}{R_S} \left[ \left( \frac{r_{\pi}}{\beta+1} \parallel R_E \parallel R_S \right) \right]$$

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### Small-Signal Equivalent Circuit: Common Base

Subst into  $\Delta$  given

$$\frac{v_o}{v_s} = +g_m \left( \frac{1}{R_s} \right) (R_c \parallel R_L) \left[ \left( \frac{r_\pi}{1+\beta} \right) \parallel R_E \parallel R_s \right]$$

Note: For  $R_s$  small: eg  $R_s \ll R_E \approx \frac{r_\pi}{1+\beta}$

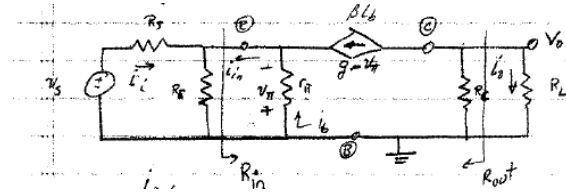
$$\boxed{\frac{v_o}{v_s} \approx +g_m (R_c \parallel R_L) \left[ \frac{R_s}{R_s} \right]}$$

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### Common Base



D. Input : Output Impedance

$$R_{in} = \frac{v_\pi}{i_{in}} = \frac{i_b r_\pi}{i_b + \beta i_b} = \boxed{\frac{r_\pi}{1+\beta}} \quad \text{small}$$

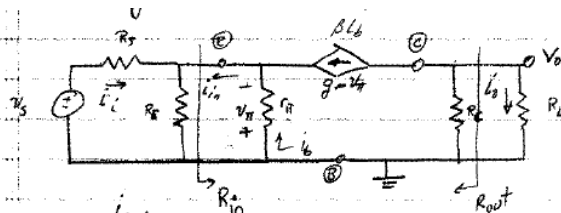
$$\boxed{R_{out} = R_c} \quad \text{assuming } r_o = \infty$$

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### Common Base



$$A_i = \frac{i_o}{i_i}$$

$$i_o = -g_m v_\pi \left( \frac{R_c}{R_c + R_L} \right) \quad \text{by current division}$$

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### Common Base

$$\text{KCL at } \textcircled{E} \text{ node: } i_i + \frac{v_\pi}{R_E} + \frac{v_\pi}{r_\pi} + g_m v_\pi = 0$$

$$v_\pi \left[ \frac{1}{R_E} + \frac{1}{r_\pi} + \beta \right] = -i_i$$

$$v_\pi = -i_i \left( R_E \parallel \frac{r_\pi}{1+\beta} \right)$$

$$\text{So } A_i = \frac{i_o}{i_i} = g_m \left( \frac{R_c}{R_c + R_L} \right) \left[ \left( \frac{r_\pi}{1+\beta} \right) \parallel R_E \right]$$

$$= \left( \frac{R_c}{R_c + R_L} \right) \left[ \left( \frac{g_m r_\pi}{1+\beta} \right) \parallel R_E \right]$$

conversely for small  $R_L$   $\approx 1$ , but  $< 1$

$$\approx \frac{\beta}{1+\beta} = \alpha$$

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### Summary of 3 Amplifiers

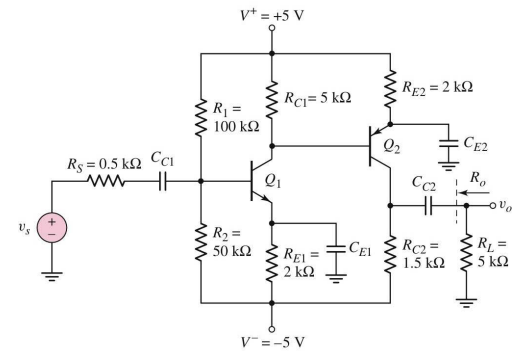
| Config                 | $A_v$           | $A_i$           | $R_i$                        | $R_o$   |
|------------------------|-----------------|-----------------|------------------------------|---|
| C-E                    | $A_v > 1$       | $A_i > 1$       | (low $k\Omega$ )<br>Moderate | (high but function of $R_C$ )<br>Mod to $H_i$ |
| C-C (emitter follower) | $A_v \approx 1$ | $A_i > 1$       | (50-100k)<br>High            | (10s $\Omega$ )<br>Low                        |
| CB                     | $A_v > 1$       | $A_v \approx 1$ | (10s $\Omega$ )<br>Low       | (high but function of $R_C$ )<br>Mod to $H_i$ |

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### Common Emitter Cascade Amplifier

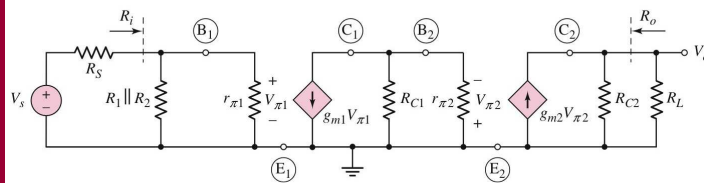


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### Small-Signal Equivalent Circuit: Cascade Amplifier

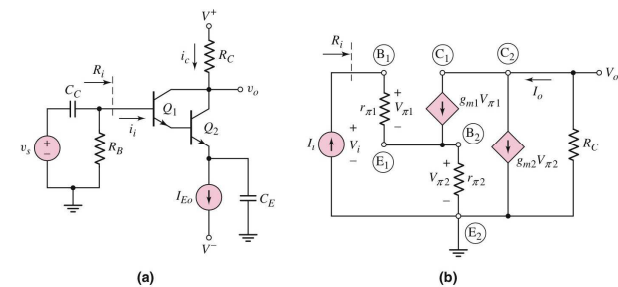


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### Darlington Pair



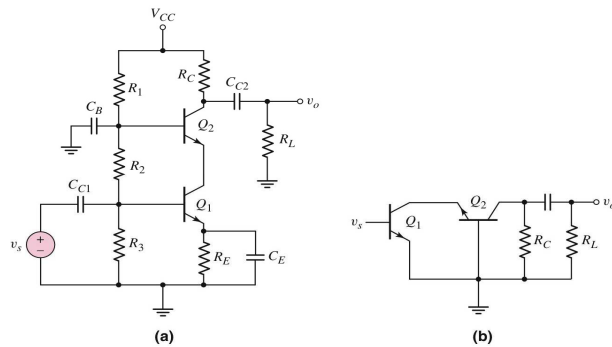
$$A_i \approx \beta_1 \beta_2$$

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## Cascode Amplifier

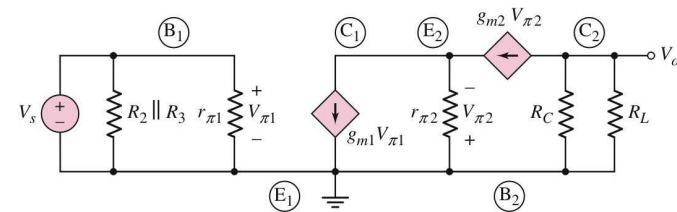


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## Small-Signal Equivalent Circuit: Cascode Amplifier



$$A_v \cong -g_{m1}(R_C \parallel R_L)$$

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